

Attorney Docket No.: SAM-0449 Application Serial No.: 10/697,826 Reply to Office Action of: July 27, 2005

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Young-gun Ko, et al.

Examiner: Crane, Sara W.

Serial No.:

10/697,826

Group Art Unit: 2811

Filing Date:

October 30, 2003

Title:

MOS TRANSISTOR WITH ELEVATED SOURCE AND DRAIN

STRUCTURES AND METHOD OF FABRICATION THEREOF

## CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

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12-14-05

Date

Vanessa Marakas

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **AMENDMENT A**

Sir:

The following is in response to the Office Action dated July 27, 2005, and the updated Office Action dated October 18, 2005, and is filed within the shortened statutory period of three months, which was reset by the updated Office Action dated October 18, 2005 to be January 18, 2006. Please amend the application as follows.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Remarks/Arguments begin on page 9 of this paper.